NSN 5961-01-213-4392

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-213-4392 **Inclosure Material:** Glass **Overall Length:** 0.250 inches **Terminal Length:** 0.700 inches **Overall Diameter:** 0.085 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 breakdown voltage, dc and 38.0 reverse voltage, instantaneous **Voltage Tolerance In Percent:** -5.0/+5.0 **Current Rating Per Characteristic:** 60.00 milliamperes repetitive peak forward current **Power Rating Per Characteristic:** 3.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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